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** CONTINUING DATA *****

~~None.~~ *wlc*

** FOREIGN APPLICATIONS *****

REPUBLIC OF KOREA 2002-81480 12/18/2002 ~~of~~*wlc*

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** 12/23/2003

Foreign Priority claimed 35 USC 119 (a-d) conditions met	<input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> yes <input checked="" type="checkbox"/> no <input type="checkbox"/> Met after allowance	STATE OR COUNTRY KOREA, REPUBLIC OF	SHEETS DRAWING 5	TOTAL CLAIMS 12	INDEPENDENT CLAIMS 2
Verified and Acknowledged Examiner's Signature <i>WLC</i>	Initials <i>WLC</i>				

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TITLE

Method of forming a buffer dielectric layer in a semiconductor device and a method of manufacturing a thin film transistor using the same

All Fees